## NSN 5961-01-584-6369

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Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
-2.3 gate to source voltage
Current Rating Per Characteristic:
10.00 milliamperes forward gate current
Power Rating Per Characteristic:
300.0 milliwatts collector power dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Product Name:
N-channel jfet circuit
Special Features:
Hermetically sealed; military option; over-voltage protection; high performance jfet; 400 g fs min (us)
Terminal Type And Quantity:
4 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0